TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74HC365AP, TC74HC365AF TC74HC366AP, TC74HC366AF

HEX BUS BUFFER TC74HC365AP/AF NON-INVERTED (3-STATE) TC74HC366AP/AF INVERTED (3-STATE)

The TC74HC365A and TC74HC366A are high speed CMOS 3 - STATE BUFFERs fabricated with silicon gate C2MOS technology.

They achieve the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

The TC74HC366A is an inverting type, while the TC74HC365A is non-inverting.

All six buffers are controlled by the combination of two enable inputs ($\overline{G}1$ and $\overline{G}2$); the outputs of these buffers are enabled only when both $\overline{G}1$ and $\overline{G}2$ inputs held low, and at the other combinations, these outputs are disabled to the high impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

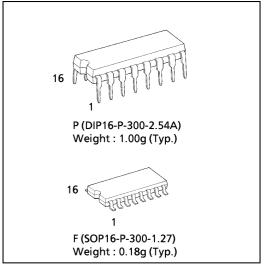
FEATURES:

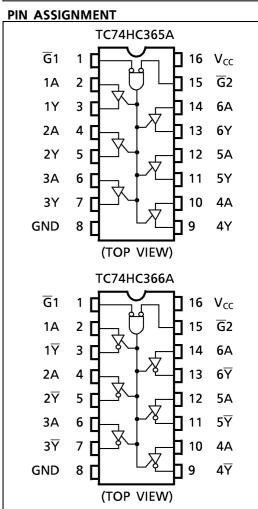
- High Speed-----tpd = 9ns(typ.) at $V_{CC} = 5V$
- Low Power Dissipation ············· $I_{CC} = 4\mu A(Max.)$ at Ta = 25°C
- High Noise Immunity $V_{NIH} = V_{NIL} = 28\% V_{CC}$ (Min.)
- Output Drive Capability 15 LSTTL Loads
- Symmetrical Output Impedance… | I_{OH} | = I_{OL} = 6mA(Min.)
- Balanced Propagation Delays $\cdots t_{pLH} \approx t_{pHL}$
- Wide Operating Voltage Range ···· V_{CC} (opr.) = 2V~6V
- Open Drain Structure
- Pin and Function Compatible with 74LS365/366

TRUTH TABLE

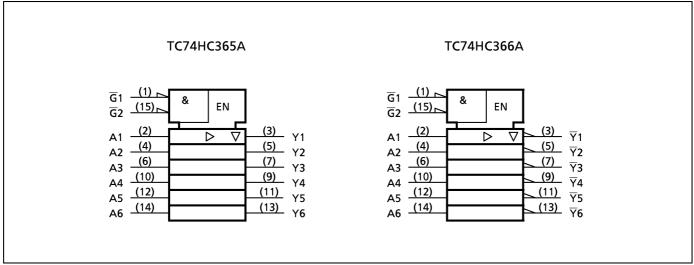
	INPUTS		OUTPUTS				
G ₁	G2	An	Yn(365A)	<u>Yn</u> (366A)			
L	L	L	L	Н			
L	L	Н	Н	L			
Н	Х	Х	Z	Z			
Х	Н	Х	Z	Z			

X: Don't Care, Z: High Impedance





IEC LOGIC SYMBOL



ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage Range	V_{CC}	− 0.5~7	٧
DC Input Voltage	V _{IN}	$-0.5 \sim V_{CC} + 0.5$	٧
DC Output Voltage	V _{OUT}	$-0.5 \sim V_{CC} + 0.5$	V
Input Diode Current	I _{IK}	± 20	mA
Output Diode Current	I _{OK}	± 20	mA
DC Output Current	I _{OUT}	±35	mA
DC V _{CC} / Ground Current	I _{cc}	± 75	mA
Power Dissipation	P _D	500 (DIP)* / 180 (SOP)	mW
Storage Temperature	T _{stg}	−65~150	°C

*500mW in the range of Ta= $-40^{\circ}\text{C}\sim65^{\circ}\text{C}$. From Ta=65°C to 85°C a derating factor of $-10\text{mW}/^{\circ}\text{C}$ shall be applied until 300mW.

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	VALUE	UNIT
Supply Voltage	V _{cc}	2~6	٧
Input Voltage	V _{IN}	0∼V _{CC}	٧
Output Voltage	V _{OUT}	0~V _{CC}	٧
Operating Temperature	T _{opr}	−40~85	°C
Input Rise and Fall Time	t _r , t _f	$0 \sim 1000 (V_{CC} = 2.0V)$ $0 \sim 500 (V_{CC} = 4.5V)$ $0 \sim 400 (V_{CC} = 6.0V)$	ns

DC ELECTRICAL CHARACTERISTICS

PARAMETER	SYMBOL TEST CO		NDITION	V _{cc}	T	Ta = 25°C		Ta = −40~85°C		UNIT
PARAIVIETER	STIVIBUL	TEST CONDITION		(V)	MIN.	TYP.	MAX.	MIN.	MAX.	OINIT
High - Level Input Voltage	V _{IH}		2.0 4.5 6.0	1.50 3.15 4.20	111		1.50 3.15 4.20		<	
Low - Level Input Voltage	V _{IL}				_ _ _		0.50 1.35 1.80		0.50 1.35 1.80	٧
High - Level Output Voltage	V _{OH}	V _{IN} = V _{IH} or V _{IL}	$I_{OH} = -20\mu A$	2.0 4.5 6.0	1.9 4.4 5.9	2.0 4.5 6.0	_ _ _	1.9 4.4 5.9	_ _ _	v
			$I_{OH} = -6 \text{ mA}$ $I_{OH} = -7.8 \text{ mA}$	4.5 6.0	4.18 5.68	4.31 5.80	=	4.13 5.63	=	
Low - Level Output Voltage	$V_{OL} \qquad V_{IN} = V_{IH} \text{ or } V_{IL}$	V _{I N} =	$I_{OL} = 20 \mu A$	2.0 4.5 6.0	111	0.0 0.0 0.0	0.1 0.1 0.1	_ _ _	0.1 0.1 0.1	\ \
		$I_{OL} = 6$ mA $I_{OL} = 7.8$ mA	4.5 6.0	1	0.17 0.18	0.26 0.26	_	0.33 0.33		
3 - State Output Off - State Current	l _{oz}	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $V_{OUT} = V_{CC} \text{ or GND}$		6.0	_	_	± 0.5	_	± 5.0	
Input Leakage Current	I _{I N}	$V_{IN} = V_{CC}$ or GND		6.0	_	l	± 0.1	_	± 1.0	μ A
Quiescent Supply Current	I _{CC}	$V_{IN} = V_{CC}$	6.0	_	_	4.0	_	40.0		

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AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 6ns$)

PARAMETER	SYMBOL	TEST		Ta = 25°C			$Ta = -40 \sim 85$ °C		UNIT	
PARAIVIETER	STIVIBUL	CONDITION	CL (pF)	V _{CC} (V)	MIN.	TYP.	MAX.	MIN.	MAX.	UIVII
Output Transition Time	t _{TLH} t _{THL}		50	2.0 4.5 6.0	_ 	20 6 5	60 12 10	_ _ _	75 15 13	
Propagation Delay Time	t _{pLH}		50	2.0 4.5 6.0	_ _ _	38 12 10	90 18 15	_ _ _	115 23 20	
Propagation Delay Time	t _{pHL}		150	2.0 4.5 6.0		51 17 14	130 26 22	_ _ _	165 33 28	ns
Output Fachla Time	t _{pZL}		50	2.0 4.5 6.0		56 17 13	130 26 22	_ _ _	165 33 28	113
Output Enable Time	t _{pZH}	$R_L = 1k\Omega$	150	2.0 4.5 6.0		69 22 17	170 34 29	_ _ _	215 44 37	
Output Disable Time	t _{pLZ} t _{pHZ}	$R_L = 1k\Omega$	50	2.0 4.5 6.0	 - -	42 18 15	130 26 22	_ _ _	165 33 28	
Input Capacitance	C _{IN}		•		_	5	10	_	10	
Output Capacitance	C _{OUT}				_	10	_	_	_	рF
Power Dissipation Capacitance	C _{PD} (1)				-	25	_	_	_	1

Note (1) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

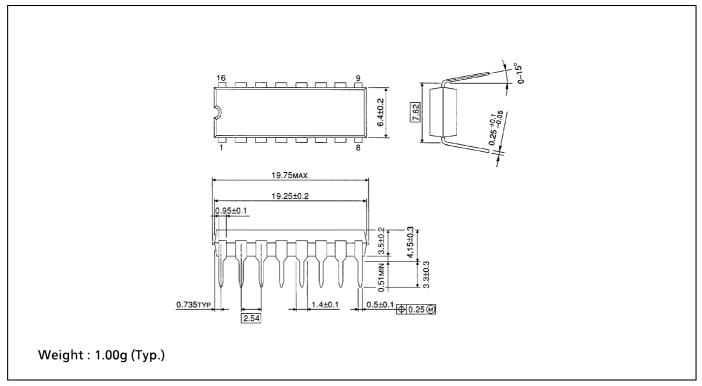
Average operating current can be obtained by the equation:

 I_{CC} (opr) = $C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC} / 6$ (per Gate)

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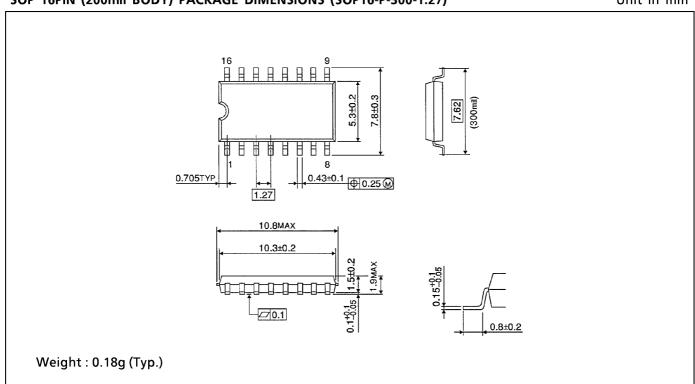
DIP 16PIN PACKAGE DIMENSIONS (DIP16-P-300-2.54A)

Unit in mm



SOP 16PIN (200mil BODY) PACKAGE DIMENSIONS (SOP16-P-300-1.27)

Unit in mm



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